



PBSS5112PAP

120 V, 1 A PNP/PNP low V_{CEsat} (BISS) transistor

30 November 2012

Product data sheet

1. Product profile

1.1 General description

PNP/PNP low V_{CEsat} Breakthrough In Small Signal (BISS) transistor in a leadless medium power DFN2020-6 (SOT1118) Surface-Mounted Device (SMD) plastic package. NPN/PNP complement: PBSS4112PANP. NPN/NPN complement: PBSS4112PAN.

1.2 Features and benefits

- Very low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C and I_{CM}
- High collector current gain h_{FE} at high I_C
- Reduced Printed-Circuit Board (PCB) requirements
- High energy efficiency due to less heat generation
- AEC-Q101 qualified

1.3 Applications

- Load switch
- Battery-driven devices
- Power management
- Charging circuits
- Power switches (e.g. motors, fans)

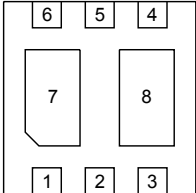
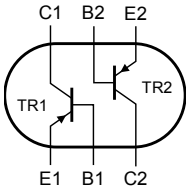
1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Per transistor						
V_{CEO}	collector-emitter voltage	open base	-	-	-120	V
I_C	collector current		-	-	-1	A
I_{CM}	peak collector current	single pulse; $t_p \leq 1$ ms	-	-	-1.5	A
V_{EBO}	emitter-base voltage	open collector	-	-	-7	V
Per transistor						
R_{CEsat}	collector-emitter saturation resistance	$I_C = -500$ mA; $I_B = -50$ mA; pulsed; $t_p \leq 300$ μ s; $\delta \leq 0.02$; $T_{amb} = 25$ °C	-	-	440	m Ω

2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1	 Transparent top view DFN2020-6 (SOT1118)	 sym138
2	B1	base TR1		
3	C2	collector TR2		
4	E2	emitter TR2		
5	B2	base TR2		
6	C1	collector TR1		
7	C1	collector TR1		
8	C2	collector TR2		

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PBSS5112PAP	DFN2020-6	plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals; body 2 x 2 x 0.65 mm	SOT1118

4. Marking

Table 4. Marking codes

Type number	Marking code
PBSS5112PAP	2S

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per transistor					
V_{CBO}	collector-base voltage	open emitter	-	-120	V
V_{CEO}	collector-emitter voltage	open base	-	-120	V
V_{EBO}	emitter-base voltage	open collector	-	-7	V
I_C	collector current		-	-1	A
I_{CM}	peak collector current	single pulse; $t_p \leq 1$ ms	-	-1.5	A
I_B	base current		-	-0.3	A

Symbol	Parameter	Conditions		Min	Max	Unit
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms		-	-1	A
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	370	mW
			[2]	-	570	mW
			[3]	-	530	mW
			[4]	-	700	mW
			[5]	-	450	mW
			[6]	-	760	mW
			[7]	-	700	mW
			[8]	-	1450	mW
Per device						
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	510	mW
			[2]	-	780	mW
			[3]	-	730	mW
			[4]	-	960	mW
			[5]	-	620	mW
			[6]	-	1040	mW
			[7]	-	960	mW
			[8]	-	2000	mW
T _j	junction temperature		-	150	°C	
T _{amb}	ambient temperature		-55	150	°C	
T _{stg}	storage temperature		-65	150	°C	

- [1] Device mounted on an FR4 PCB, single-sided 35 µm copper strip line, tin-plated and standard footprint.
 [2] Device mounted on an FR4 PCB, single-sided 35 µm copper strip line, tin-plated, mounting pad for collector 1 cm².
 [3] Device mounted on 4-layer PCB 35 µm copper strip line, tin-plated and standard footprint.
 [4] Device mounted on 4-layer PCB 35 µm copper strip line, tin-plated, mounting pad for collector 1 cm².
 [5] Device mounted on an FR4 PCB, single-sided 70 µm copper strip line, tin-plated and standard footprint.
 [6] Device mounted on an FR4 PCB, single-sided 70 µm copper strip line, tin-plated, mounting pad for collector 1 cm².
 [7] Device mounted on 4-layer PCB 70 µm copper strip line, tin-plated and standard footprint.
 [8] Device mounted on 4-layer PCB 70 µm copper strip line, tin-plated, mounting pad for collector 1 cm².



- (1) 4-layer PCB 70 μm, mounting pad for collector 1 cm²
- (2) FR4 PCB 70 μm, mounting pad for collector 1 cm²
- (3) 4-layer PCB 70 μm, standard footprint
- (4) 4-layer PCB 35 μm, mounting pad for collector 1 cm²
- (5) FR4 PCB 35 μm, mounting pad for collector 1 cm²
- (6) 4-layer PCB 35 μm, standard footprint
- (7) FR4 PCB 70 μm, standard footprint
- (8) FR4 PCB 35 μm, standard footprint

Fig. 1. Per transistor: power derating curves

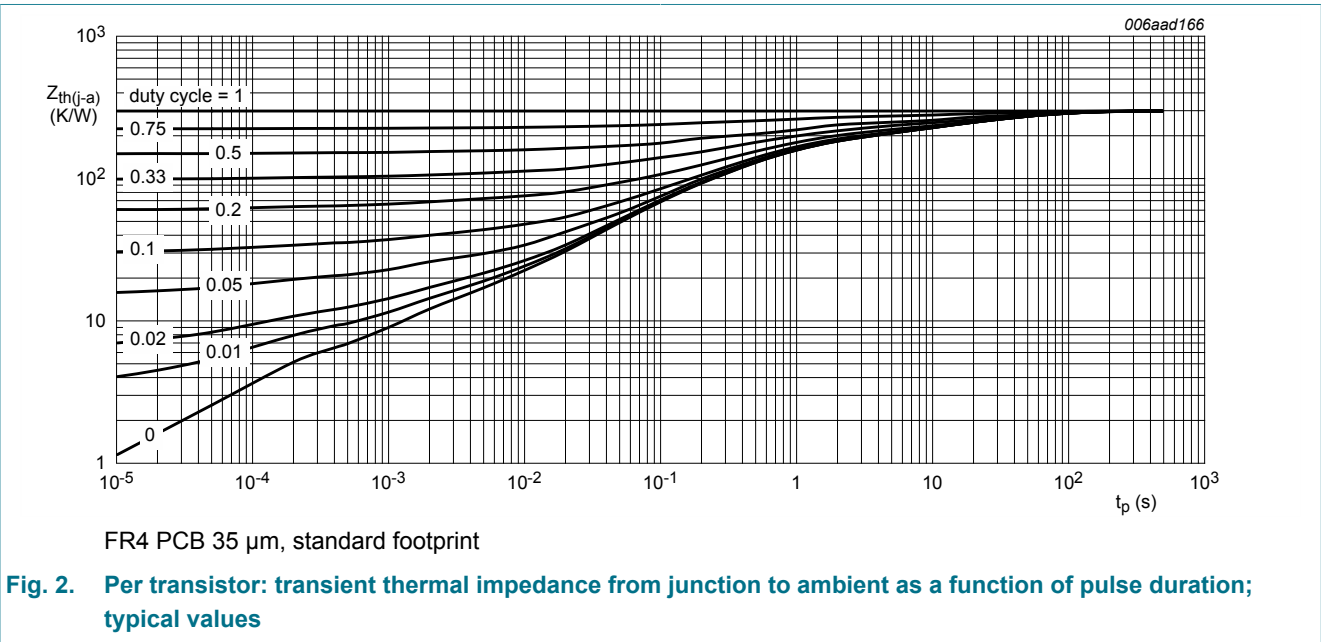
6. Thermal characteristics

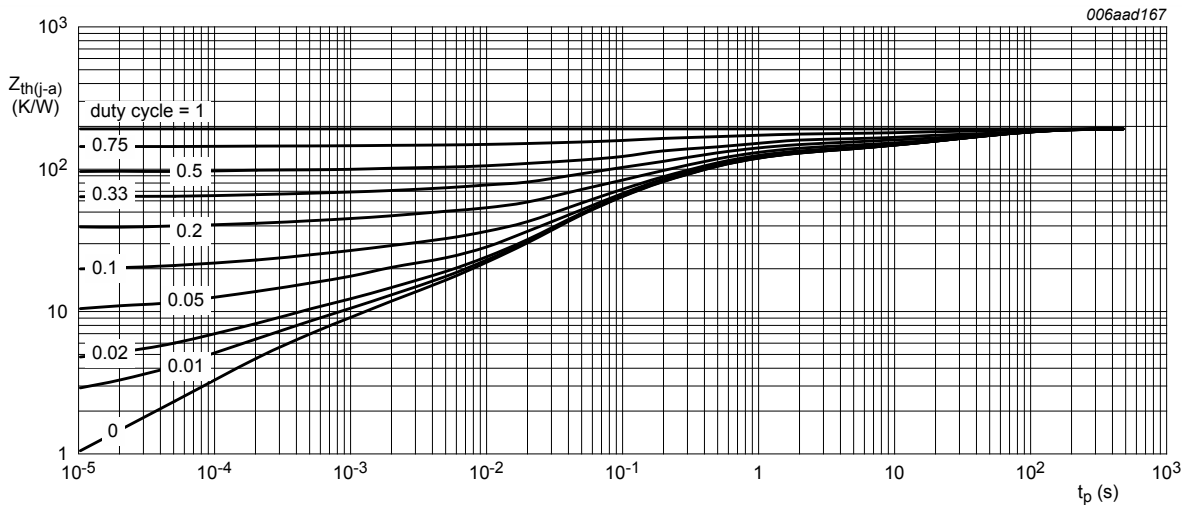
Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Per transistor							
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	338	K/W
			[2]	-	-	219	K/W
			[3]	-	-	236	K/W
			[4]	-	-	179	K/W
			[5]	-	-	278	K/W
			[6]	-	-	164	K/W
			[7]	-	-	179	K/W
			[8]	-	-	86	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	30	K/W

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Per device							
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	245	K/W
			[2]	-	-	160	K/W
			[3]	-	-	171	K/W
			[4]	-	-	130	K/W
			[5]	-	-	202	K/W
			[6]	-	-	120	K/W
			[7]	-	-	130	K/W
			[8]	-	-	63	K/W

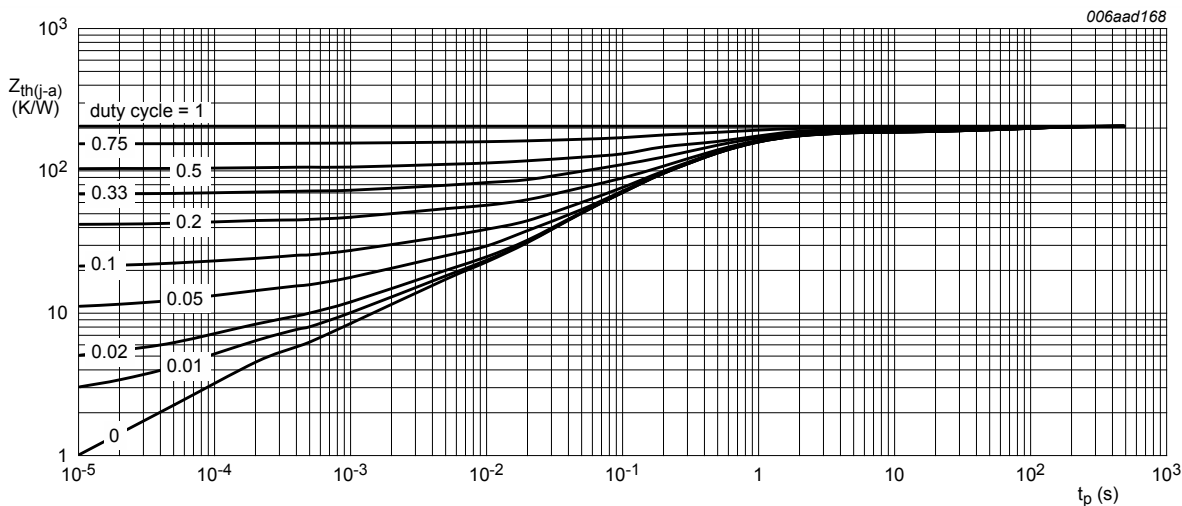
- [1] Device mounted on an FR4 PCB, single-sided 35 µm copper strip line, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided 35 µm copper strip line, tin-plated, mounting pad for collector 1 cm².
- [3] Device mounted on 4-layer PCB 35 µm copper strip line, tin-plated and standard footprint.
- [4] Device mounted on 4-layer PCB 35 µm copper strip line, tin-plated, mounting pad for collector 1 cm².
- [5] Device mounted on an FR4 PCB, single-sided 70 µm copper strip line, tin-plated and standard footprint.
- [6] Device mounted on an FR4 PCB, single-sided 70 µm copper strip line, tin-plated, mounting pad for collector 1 cm².
- [7] Device mounted on 4-layer PCB 70 µm copper strip line, tin-plated and standard footprint.
- [8] Device mounted on 4-layer PCB 70 µm copper strip line, tin-plated, mounting pad for collector 1 cm².





FR4 PCB 35 μ m, mounting pad for collector 1 cm²

Fig. 3. Per transistor: transient thermal impedance from junction to ambient as a function of pulse duration; typical values



4-layer PCB 35 μ m, standard footprint

Fig. 4. Per transistor: transient thermal impedance from junction to ambient as a function of pulse duration; typical values

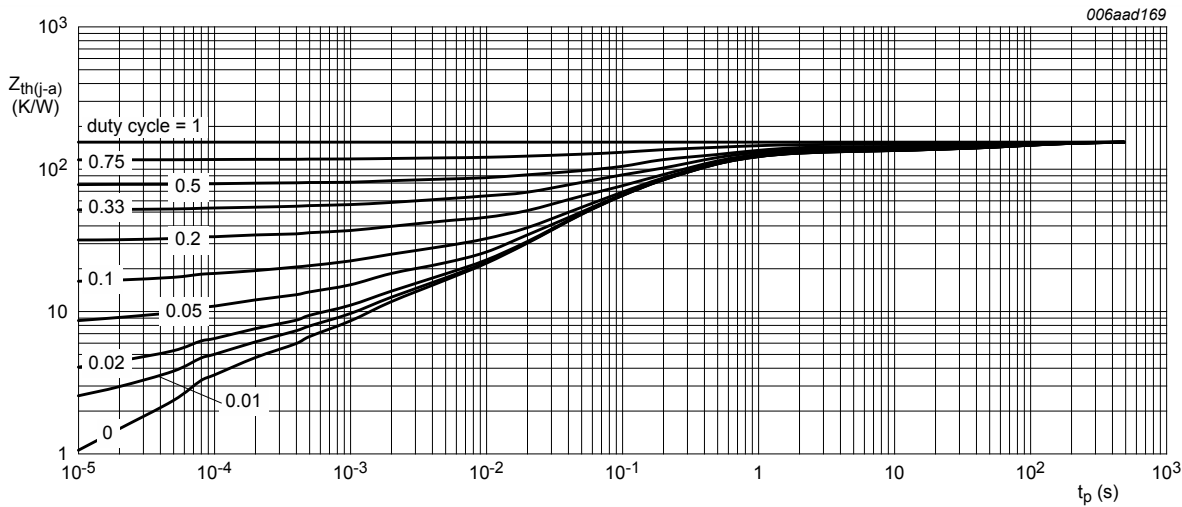


Fig. 5. Per transistor: transient thermal impedance from junction to ambient as a function of pulse duration; typical values

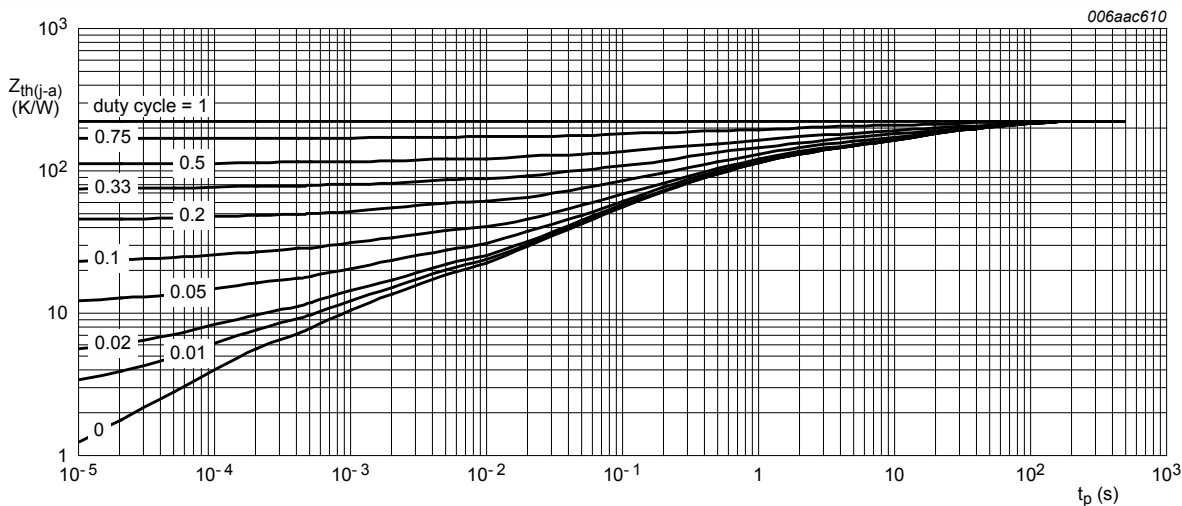
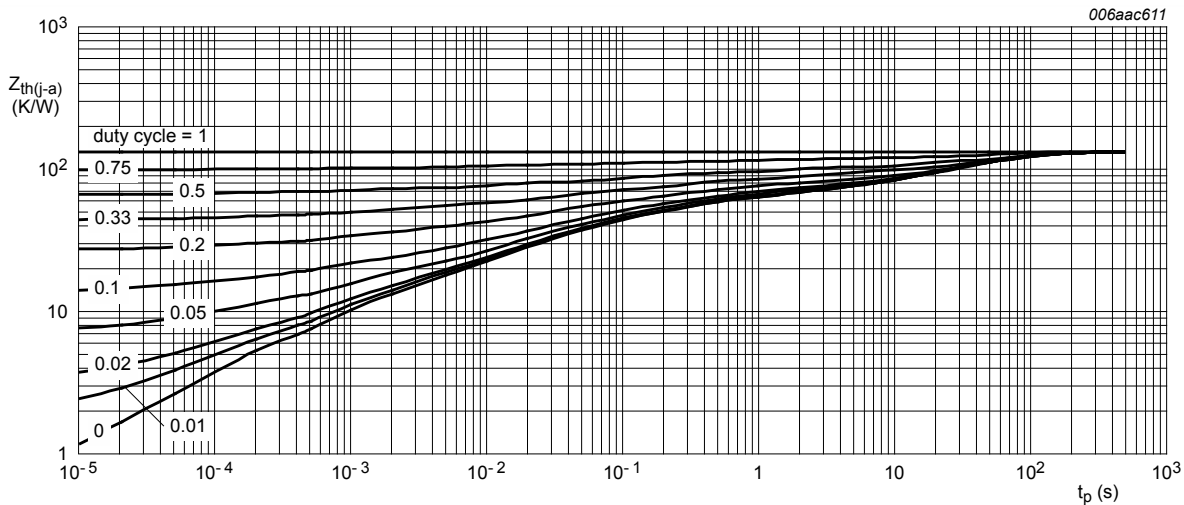
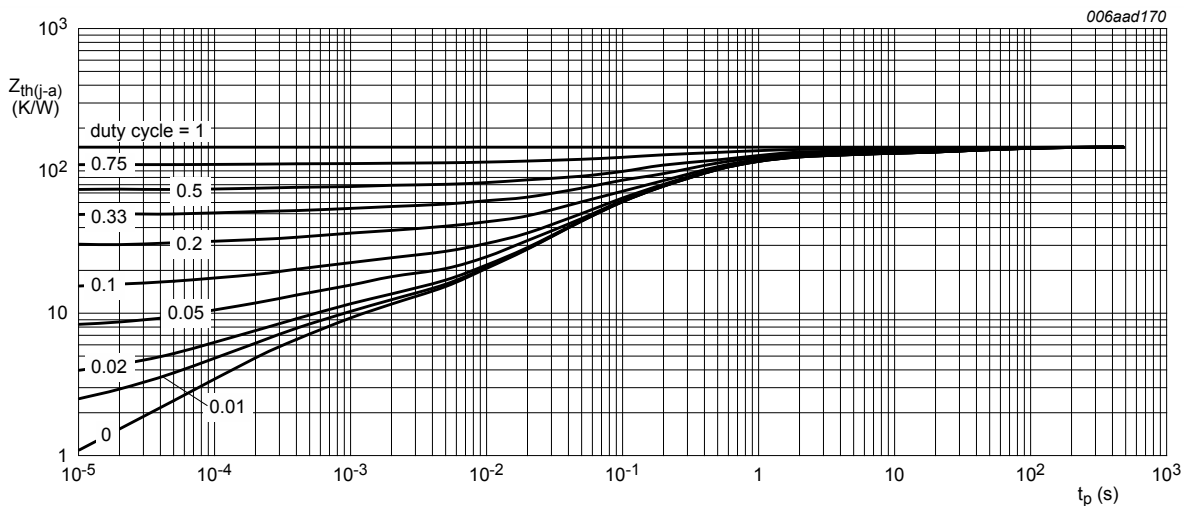


Fig. 6. Per transistor: transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB 70 μm , mounting pad for collector 1 cm^2

Fig. 7. Per transistor: transient thermal impedance from junction to ambient as a function of pulse duration; typical values



4-layer PCB 70 μm , standard footprint

Fig. 8. Per transistor: transient thermal impedance from junction to ambient as a function of pulse duration; typical values

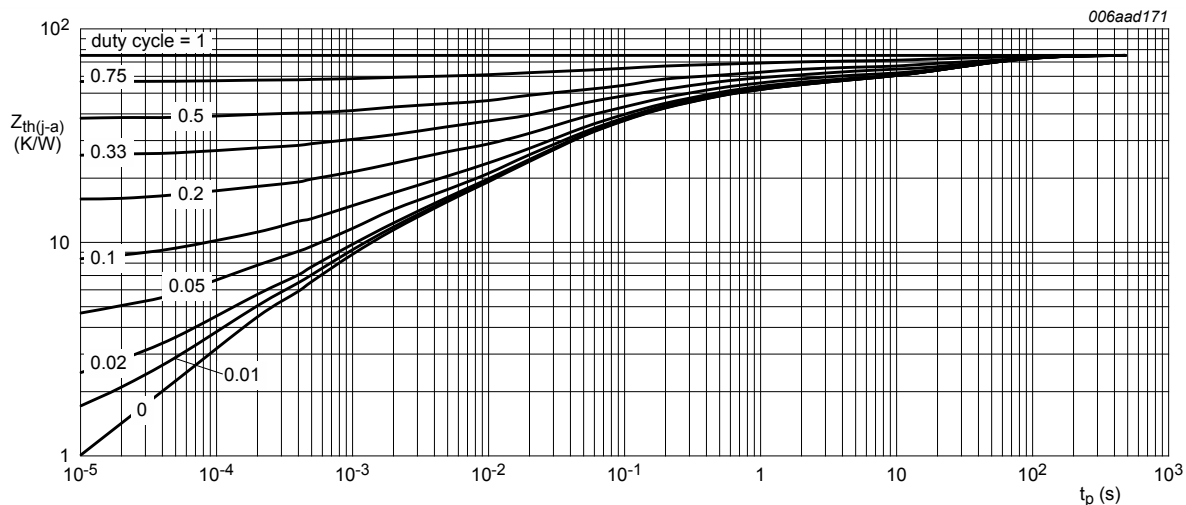


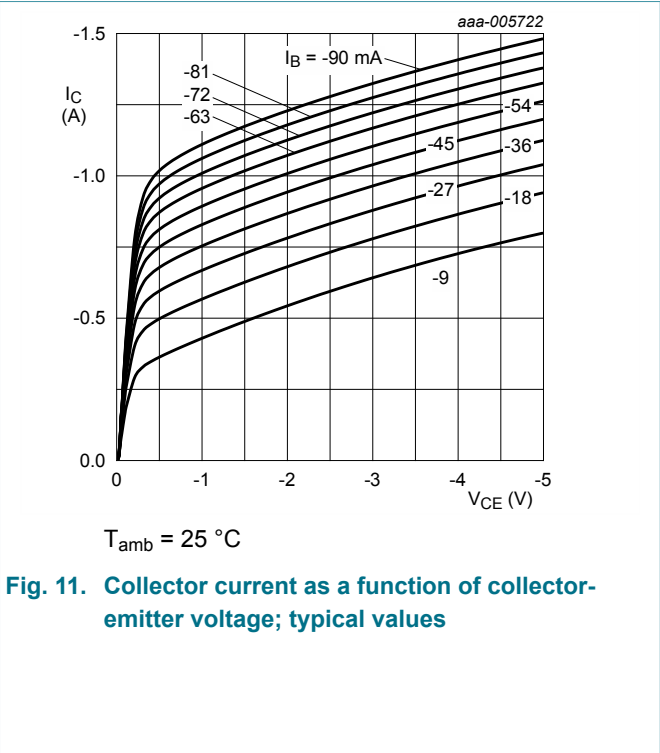
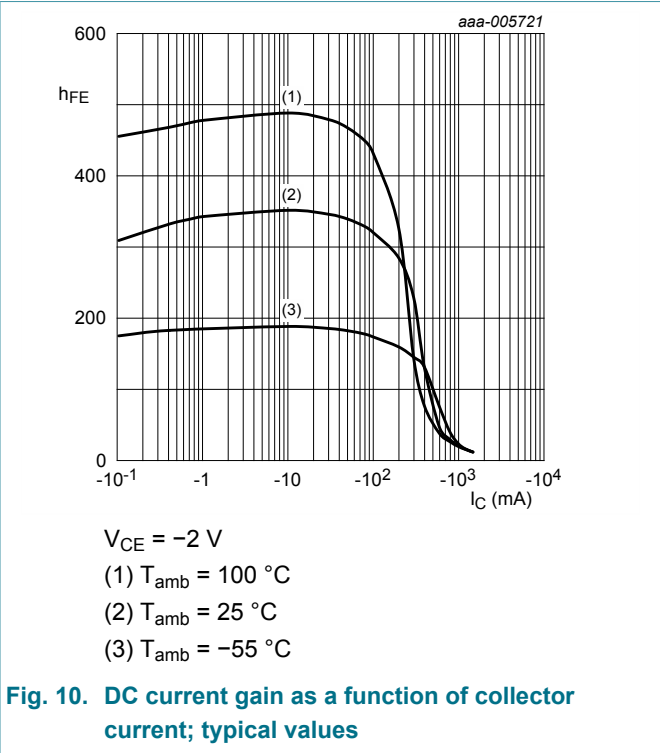
Fig. 9. Per transistor: transient thermal impedance from junction to ambient as a function of pulse duration; typical values

7. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Per transistor						
I_{CBO}	collector-base cut-off current	$V_{\text{CB}} = -96 \text{ V}; I_{\text{E}} = 0 \text{ A}; T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$	-	-	-100	nA
		$V_{\text{CB}} = -96 \text{ V}; I_{\text{E}} = 0 \text{ A}; T_{\text{j}} = 150 \text{ }^{\circ}\text{C}$	-	-	-50	μA
I_{EBO}	emitter-base cut-off current	$V_{\text{EB}} = -5 \text{ V}; I_{\text{C}} = 0 \text{ A}; T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$	-	-	-100	nA
h_{FE}	DC current gain	$V_{\text{CE}} = -2 \text{ V}; I_{\text{C}} = -100 \text{ mA}; \text{pulsed}; t_{\text{p}} \leq 300 \text{ } \mu\text{s}; \delta \leq 0.02; T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$	190	305	-	
		$V_{\text{CE}} = -2 \text{ V}; I_{\text{C}} = -500 \text{ mA}; \text{pulsed}; t_{\text{p}} \leq 300 \text{ } \mu\text{s}; \delta \leq 0.02; T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$	50	85	-	
		$V_{\text{CE}} = -2 \text{ V}; I_{\text{C}} = -1 \text{ A}; \text{pulsed}; t_{\text{p}} \leq 300 \text{ } \mu\text{s}; \delta \leq 0.02; T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$	15	25	-	
V_{CEsat}	collector-emitter saturation voltage	$I_{\text{C}} = -500 \text{ mA}; I_{\text{B}} = -50 \text{ mA}; \text{pulsed}; t_{\text{p}} \leq 300 \text{ } \mu\text{s}; \delta \leq 0.02; T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$	-	-150	-220	mV
		$I_{\text{C}} = -1 \text{ A}; I_{\text{B}} = -100 \text{ mA}; \text{pulsed}; t_{\text{p}} \leq 300 \text{ } \mu\text{s}; \delta \leq 0.02; T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$	-	-335	-480	mV
R_{CEsat}	collector-emitter saturation resistance	$I_{\text{C}} = -500 \text{ mA}; I_{\text{B}} = -50 \text{ mA}; \text{pulsed}; t_{\text{p}} \leq 300 \text{ } \mu\text{s}; \delta \leq 0.02; T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$	-	-	440	m Ω
V_{BEsat}	base-emitter saturation voltage	$I_{\text{C}} = -500 \text{ mA}; I_{\text{B}} = -50 \text{ mA}; T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$	-	-	-1	V

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
		$I_C = -1\text{ A}$; $I_B = -100\text{ mA}$; pulsed; $t_p \leq 300\text{ }\mu\text{s}$; $\delta \leq 0.02$; $T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	-	-1.1	V
V_{BEon}	base-emitter turn-on voltage	$V_{\text{CE}} = -2\text{ V}$; $I_C = -0.5\text{ A}$; pulsed; $t_p \leq 300\text{ }\mu\text{s}$; $\delta \leq 0.02$; $T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	-	-0.9	V
t_d	delay time	$V_{\text{CC}} = -10\text{ V}$; $I_C = -500\text{ mA}$; $I_{\text{Bon}} = -25\text{ mA}$; $I_{\text{Boff}} = 25\text{ mA}$; $T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	15	-	ns
t_r	rise time		-	245	-	ns
t_{on}	turn-on time		-	260	-	ns
t_s	storage time		-	290	-	ns
t_f	fall time		-	270	-	ns
t_{off}	turn-off time		-	560	-	ns
f_T	transition frequency	$V_{\text{CE}} = -10\text{ V}$; $I_C = -50\text{ mA}$; $f = 100\text{ MHz}$; $T_{\text{amb}} = 25\text{ }^\circ\text{C}$	50	100	-	MHz
C_c	collector capacitance	$V_{\text{CB}} = -10\text{ V}$; $I_E = 0\text{ A}$; $i_e = 0\text{ A}$; $f = 1\text{ MHz}$; $T_{\text{amb}} = 25\text{ }^\circ\text{C}$	-	9.5	13	pF



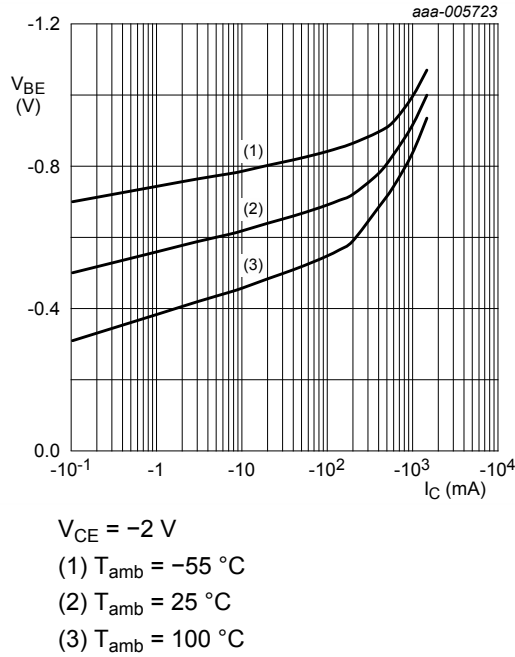


Fig. 12. Base-emitter voltage as a function of collector current; typical values

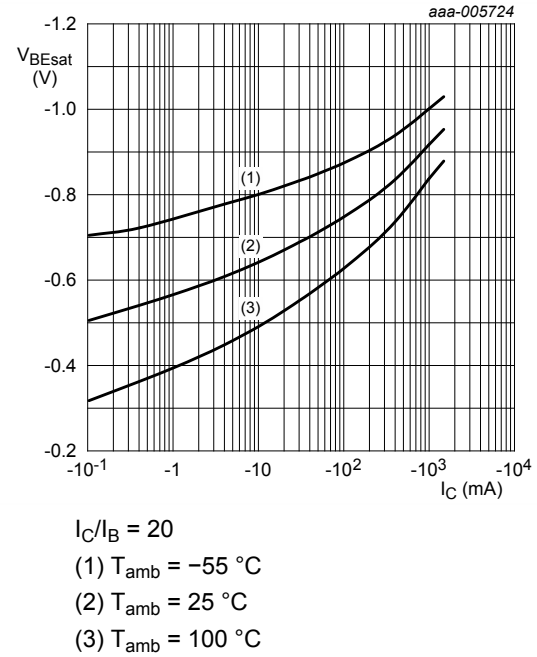


Fig. 13. Base-emitter saturation voltage as a function of collector current; typical values

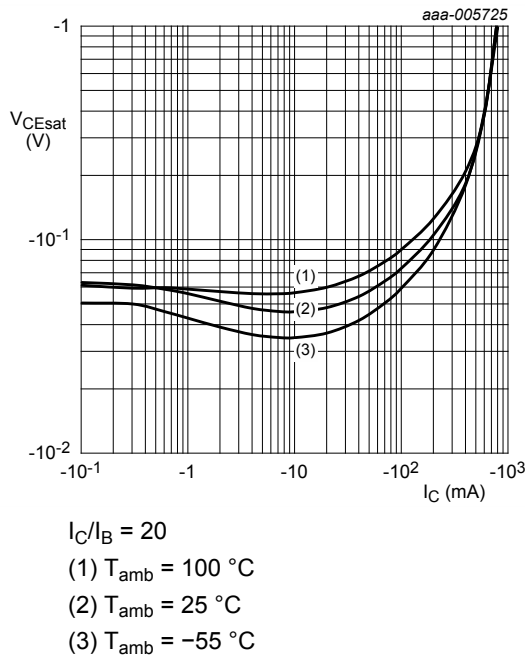


Fig. 14. Collector-emitter saturation voltage as a function of collector current; typical values

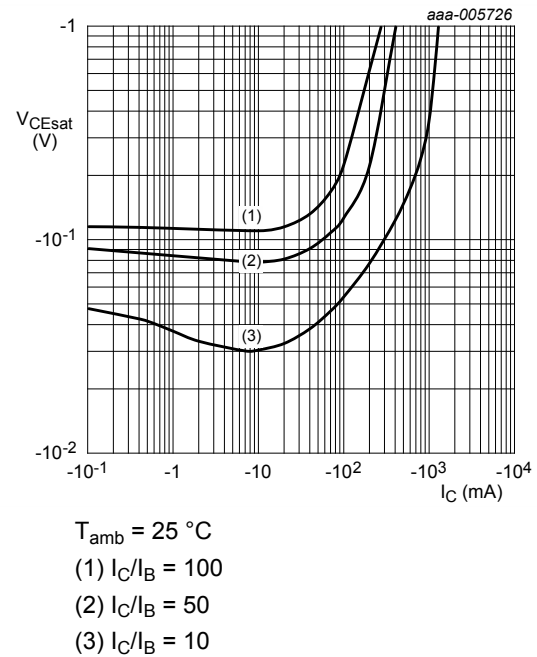
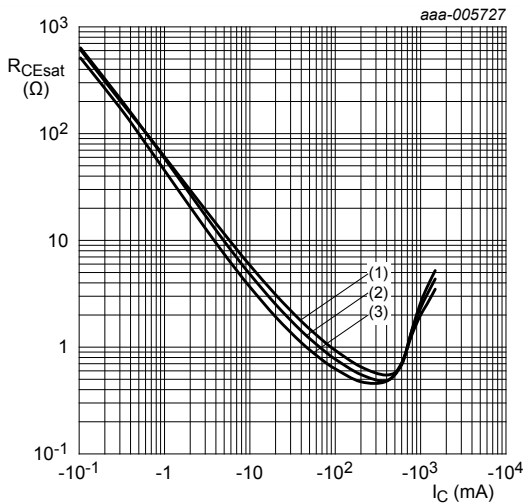
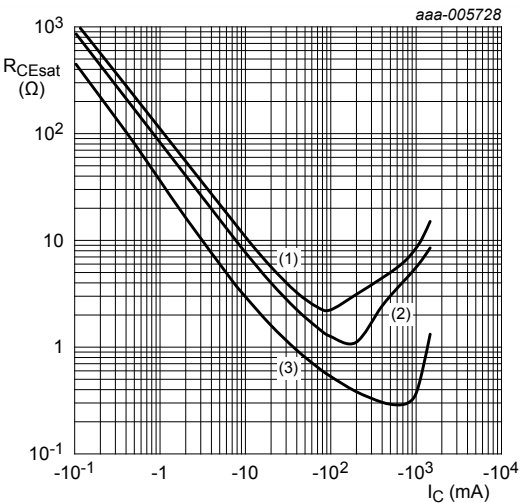


Fig. 15. Collector-emitter saturation voltage as a function of collector current; typical values



$I_C/I_B = 20$
(1) $T_{amb} = 100^\circ\text{C}$
(2) $T_{amb} = 25^\circ\text{C}$
(3) $T_{amb} = -55^\circ\text{C}$

Fig. 16. Collector-emitter saturation resistance as a function of collector current; typical values



$T_{amb} = 25^\circ\text{C}$
(1) $I_C/I_B = 100$
(2) $I_C/I_B = 50$
(3) $I_C/I_B = 10$

Fig. 17. Collector-emitter saturation resistance as a function of collector current; typical values

8. Test information

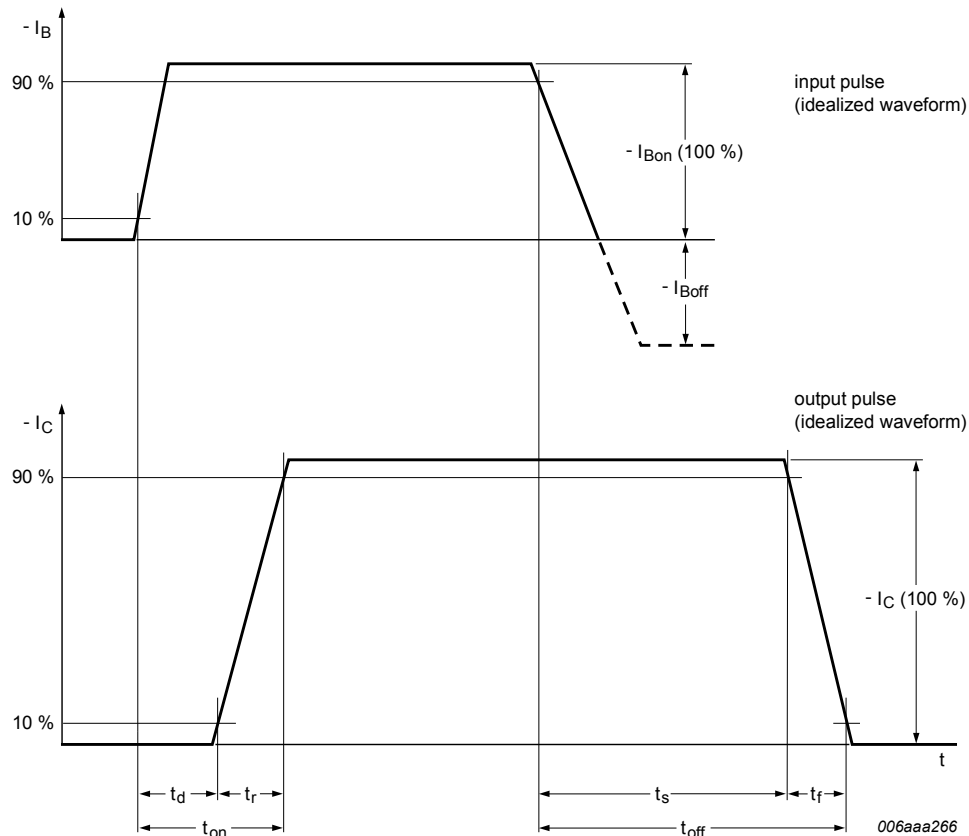


Fig. 18. BISS transistor switching time definition

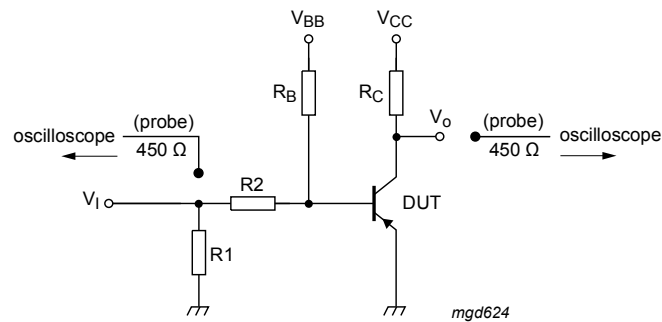
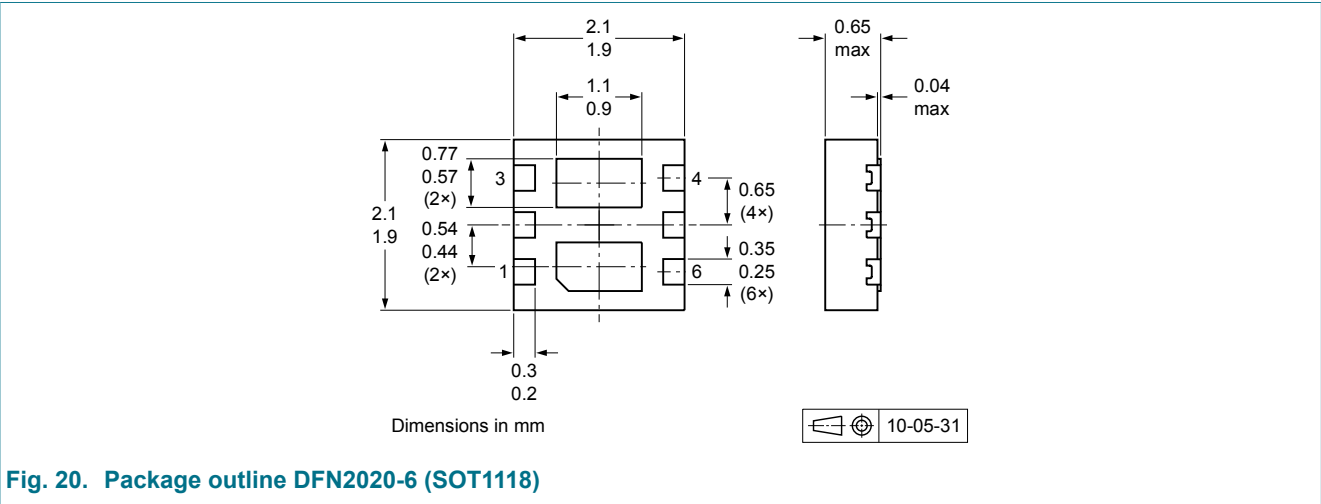


Fig. 19. Test circuit for switching times

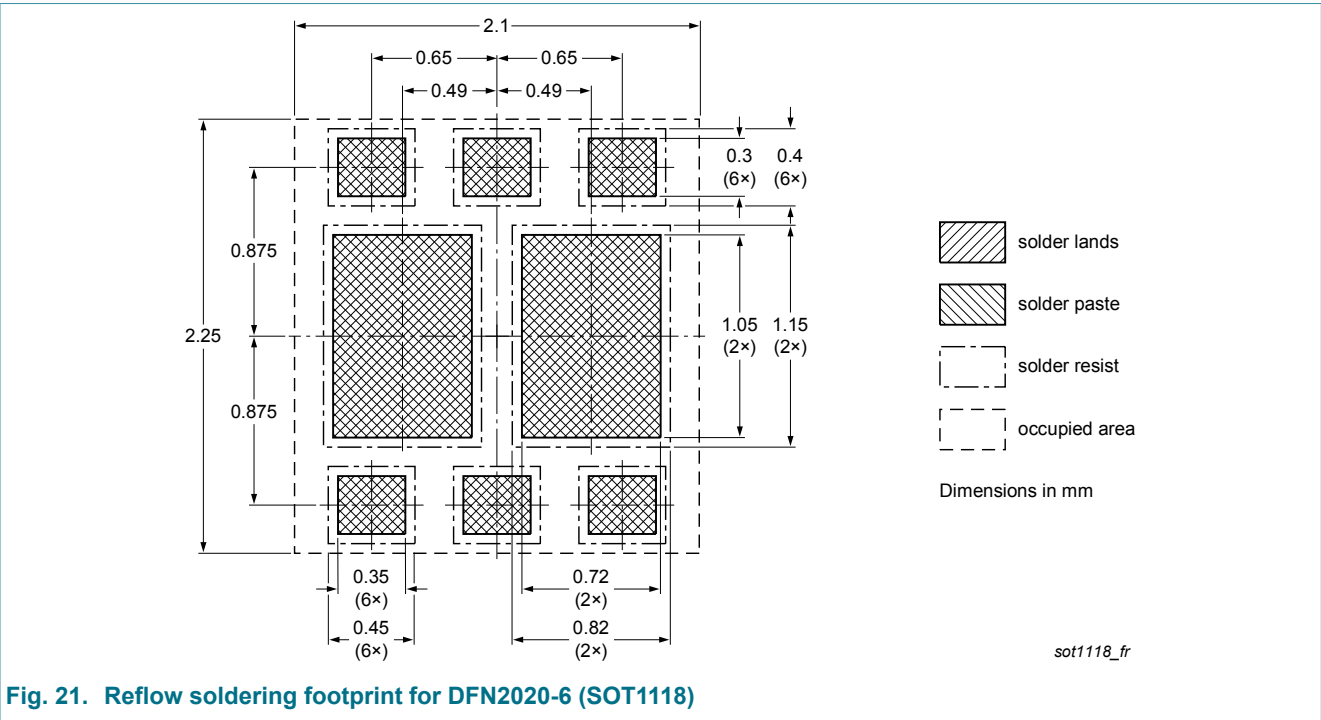
8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



10. Soldering



11. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBSS5112PAP v.1	20121130	Product data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
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